# Application Data Sh t

#### **Application Information**

Application Type:: Regular

Subject Matter:: Utility

Suggested Group Art Unit:: N/A

CD-ROM or CD-R?:: None

Sequence submission?:: None

Computer Readable Form (CRF)?:: No

Title:: METHOD FOR MANUFACTURING FLASH

MEMORY DEVICE

Attorney Docket Number:: 29936/39883

Request for Early Publication?:: No

Request for Non-Publication?:: No

Total Drawing Sheets:: 4

Small Entity?:: No

Petition included?:: No

Secrecy Order in Parent Appl.?:: No

#### **Applicant Information**

Applicant Authority Type:: Inventor

Primary Citizenship Country:: Korea, Republic of

Status:: Full Capacity

Given Name:: Byoung

Middle Name:: Ki

Family Name:: Lee

City of Residence:: Kyungki-Do

Country of Residence:: Korea

Street of mailing address:: Yooseung Apt. 201-1205, Shinha-Ri

Bubal-Uep, Ichon-shi

City of mailing address:: Kyungki-Do

Country of mailing address:: Korea, Republic of

# **Correspondence Information**

Correspondence Customer Number::

04743

**Representative Information** 

Representative Customer Number::

04743

# **Foreign Priority Information**

Country::	Application number::	FilingDate::	Priority Claimed::
Korea, Republic of	2003-43400	06/30/03	Yes

#### **Assignee Information**

Assignee name::

HYNIX SEMICONDUCTOR INC.

Street of mailing address::

San 136-1, Ami-Ri, Bubal-Uep, Ichon-Shi

City of mailing address::

Kyungki-Do

Country of mailing address::

Korea, Republic of

Postal or Zip Code of mailing address::

467-860